

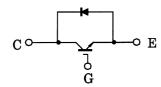
TOSHIBA INSULATED GATE BIPOLAR TRANSISTOR

ST1000EX21

HIGH POWER SWITCHING APPLICATIONS MOTOR CONTROL APPLICATIONS

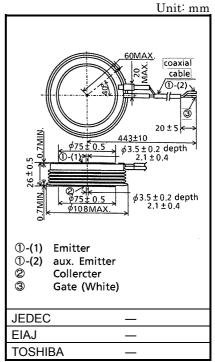
- All Electric contacts by Pressure Structure and Airtight Package
- Anti-Parallel Fast Recovery Diode in This Package
- Enhancement Mode IGBT

EQUIVALENT CIRCUIT



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V _{CES}	2500	V	
GateEmitter Voltage		V _{GES}	±20	V	
Collector Current	DC	Ι _C	1000	А	
	1ms	I _{CP}	2000	А	
Forward Current	DC	١ _F	1000	А	
	1ms	I _{FM}	2000	А	
Collector Power Dissipation (Tc = 25°C)		Pc	5550	W	
Operating Junction Temperature		Tj	-20~125	°C	
Storage Temperature Range		T _{stg}	-40~125	°C	
Mounting Force		—	31.5±3.2	kN	



Weight: 1250g

ELECTRICAL CHARACTERISTICS (Tc = 125° C without R_{th})

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Gate Leakage Current		I _{GES}	V_{GE} = ±20V, V_{CE} = 0V	_	_	±1	μA
Collector Cut-Off Current		ICES	V _{CE} = 2500V, V _{GE} = 0V	_	_	200	mA
Gate-Emitter Cut-Off Voltage		V _{GE (off)}	V _{CE} = 5V, I _C = 1A	3.0	4.5	6.0	V
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 1000A, V _{GE} = 15V	_	5.5	6.0	V
Input Capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0V, f = 1MHz	_	170	_	nF
Switching Times	Rise Time	tr		_	0.3	_	μs
	Turn-On Time	ton	Inductive load, V _{CC} = 1500V, I _C = 1000A, V _{GG} = ±15V, R _G = 5.0Ω	_	2.2	_	μs
	Fall Time	t _f		_	0.5	_	μs
	Turn-Off Time	t _{off}		_	1.7	_	μs
Forward Voltage of Diode		V _F	I _F = 1000A, V _{GE} = 0V	_	2.7	3.2	V
Reverse Recovery Time		t _{rr}	I _F = 1000A, V _{GG} = -15V, di / dt = 2600A / μs	_	0.6	_	μs
Thermal Resistance	Transistor Pant	R _{th (j−f) E}	Junction-Emitter side	_	_	47.5	°C / kW
		R _{th (j−f) C}	Junction-Collector side	_	_	29.0	°C / kW
		R _{th (j−f)} D	Junction-double side	_	—	18.0	°C / kW
	Diode Part	R _{th (j−f) A}	Junction-Anode side	—	—	125	°C / kW
		R _{th (j−f) K}	Junction-Cathode side	_	_	70.3	°C / kW
		R _{th (j−f)} D	Junction double side	—	—	45.0	°C / kW

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